

## N-CHANNEL SILICON POWER MOSFET

## FAP-2S Series

## ■ Features

- High speed switching
- Low on-resistance
- No secondary breakdown
- Low driving power
- Avalanche-proof

## ■ Applications

- Switching regulators
- UPS (Uninterruptible Power Supply)
- DC-DC converters

## ■ Maximum ratings and characteristic Absolute maximum ratings

(● (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Drain-source voltage	VDS	450	V
Continuous drain current	Id	±8	A
Pulsed drain current	Id(puls)	±32	A
Gate-source voltage	VGS	±35	V
Repetitive or non-repetitive	IAR *2	8	A
Maximum Avalanche Energy	EAS*1	215.9	mJ
Max. power dissipation	PD	50	W
Operating and storage temperature range	Tch	+150	°C
	Tstg	-55 to +150	°C

\*1 L=6.19mH, VCC=45V \*2 Tch≤150°C

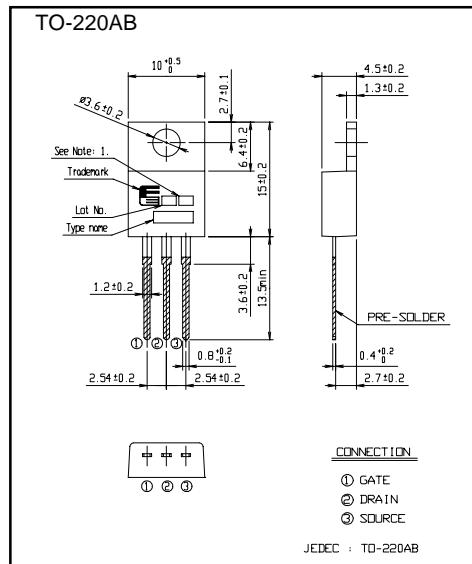
## (● Electrical characteristics (Tc =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Drain-source breakdown voltage	V(BR)DSS	Id=1mA VGS=0V	450			V
Gate threshold voltage	VGS(th)	Id=1mA VDS=VGS	3.5	4.0	4.5	V
Zero gate voltage drain current	IdSS	VDS=450V VGS=0V	10 0.2	500 1.0	500 1.0	μA mA
Gate-source leakage current	IGSS	VGS=±35V VDS=0V	10	100	100	nA
Drain-source on-state resistance	RDS(on)	Id=4A VGS=10V		1.0	1.2	Ω
Forward transconductance	gfs	Id=4A VDS=25V	2	4		S
Input capacitance	Ciss	VDS=25V	540	810		pF
Output capacitance	Coss	VGS=0V	100	150		
Reverse transfer capacitance	Crss	f=1MHz	45	70		
Turn-on time ton	td(on)	VCC=300V Id=8A	13	20		ns
	tr	VGS=10V	45	70		
Turn-off time toff	td(off)	Rgs=10Ω	40	60		
	tr		25	40		
Avalanche capability	IAV	L=6.19 mH Tch=25°C	8			A
Diode forward on-voltage	VSD	IF=2xIDR VGS=0V Tch=25°C		1.1	1.65	V
Reverse recovery time	trr	IF=IDR		450		ns
Reverse recovery charge	Qrr	-di/dt=100A/μs Tch=25°C		3.7		μC

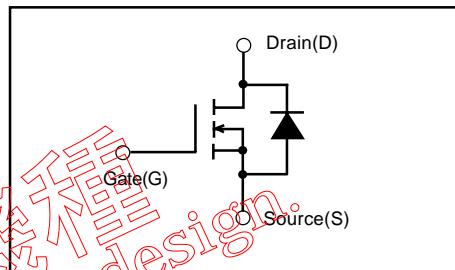
## (● Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	Rth(ch-c)	channel to case			2.50	°C/W
	Rth(ch-a)	channel to ambient			125	°C/W

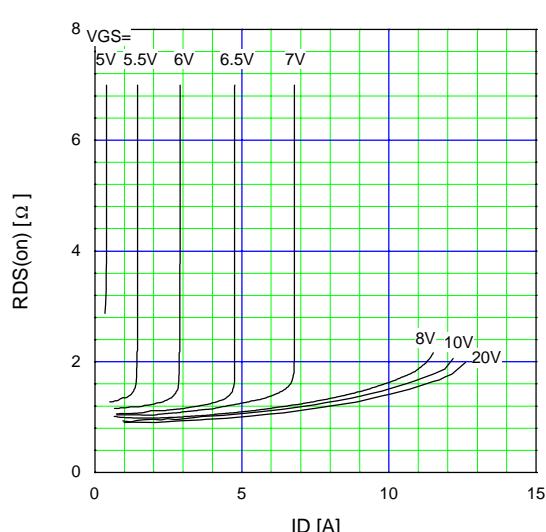
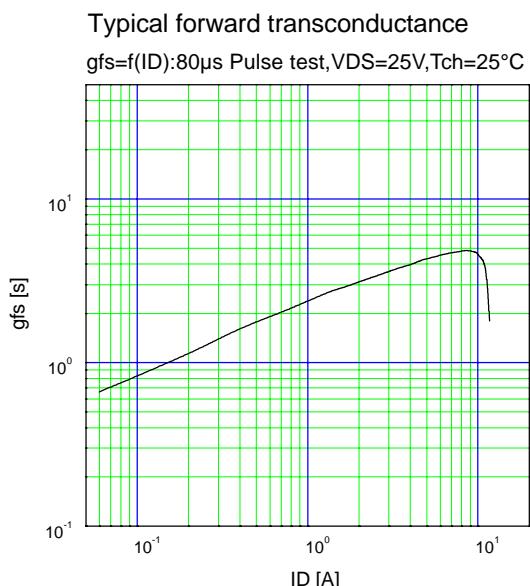
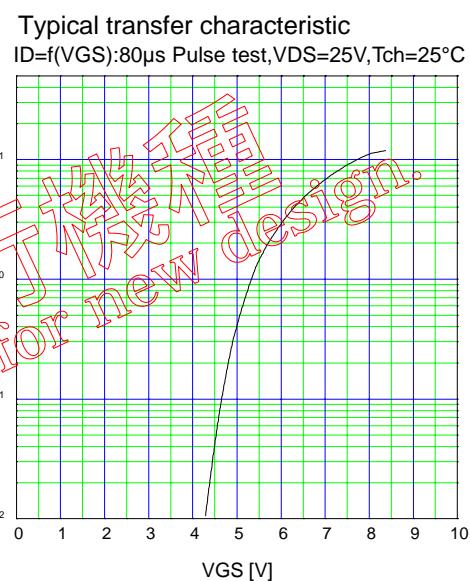
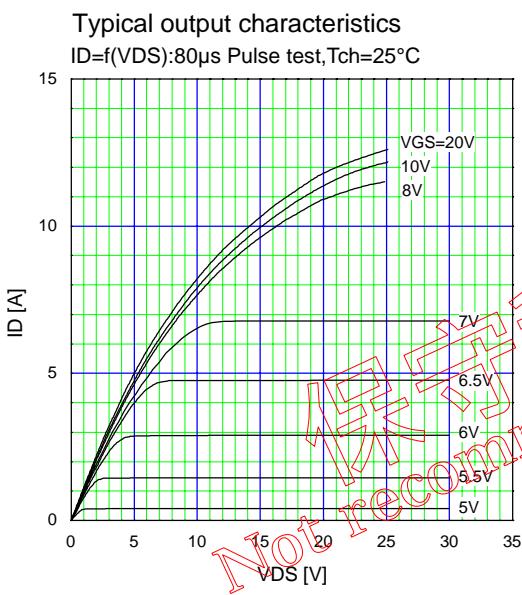
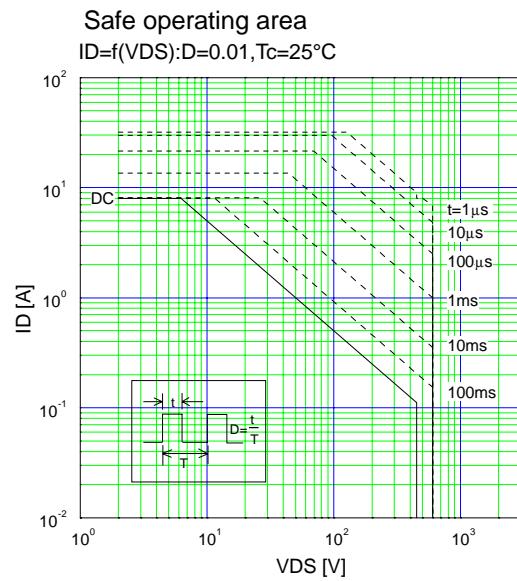
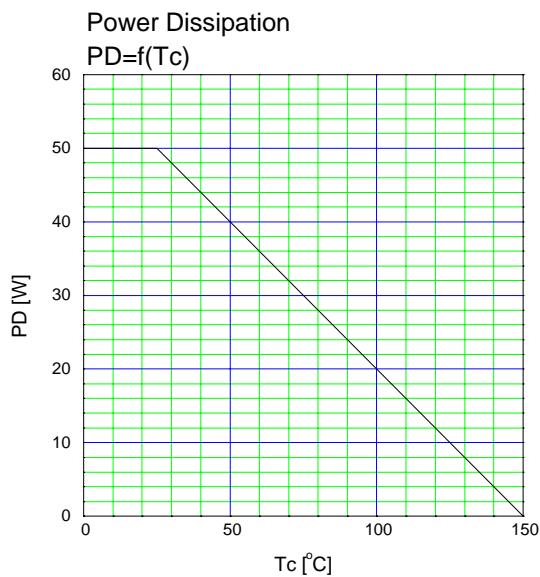
## ■ Outline Drawings

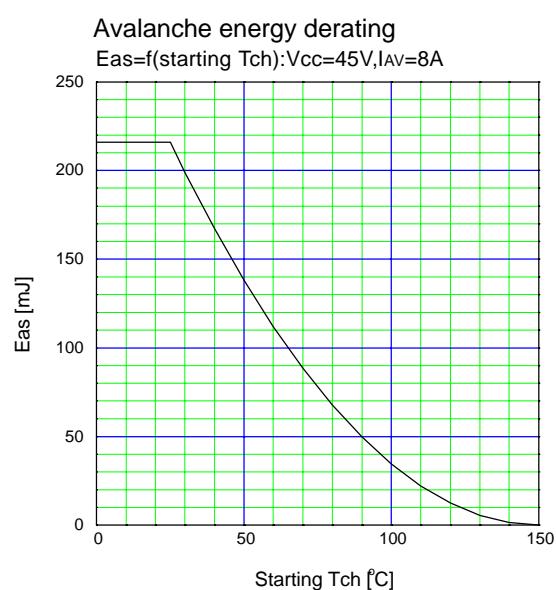
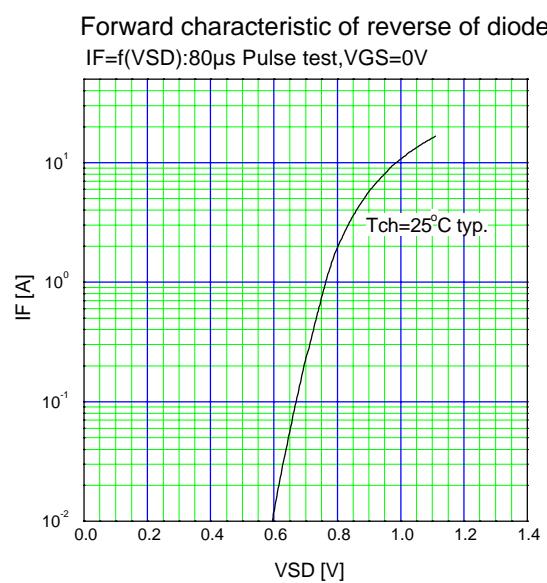
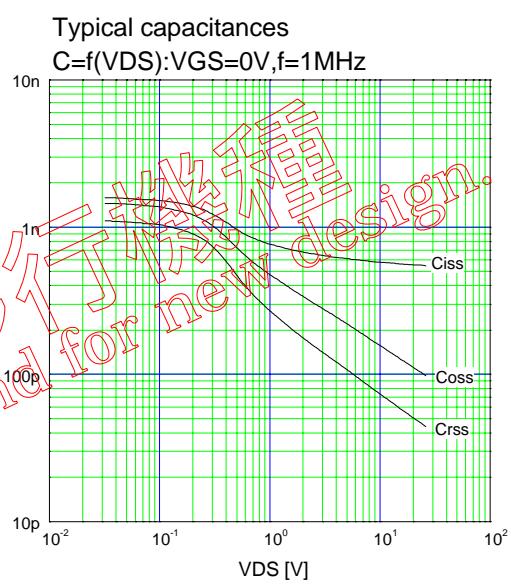
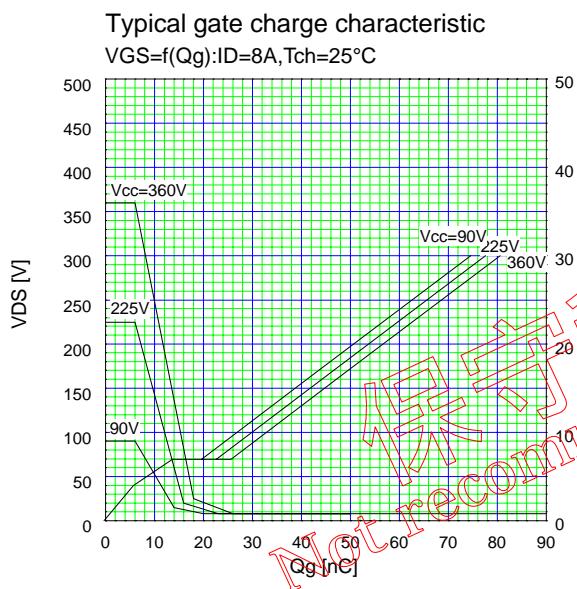
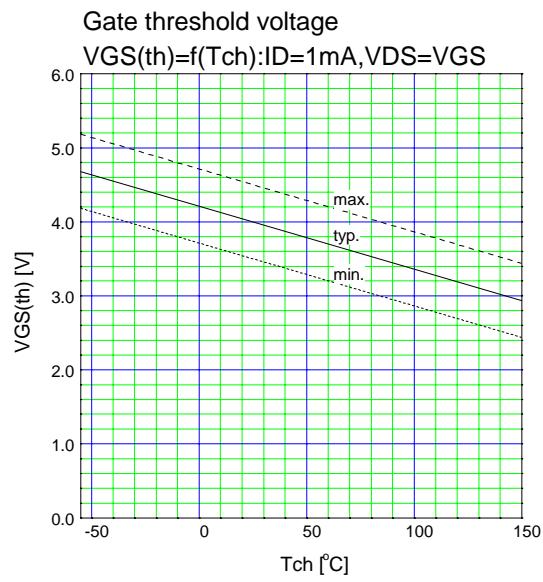
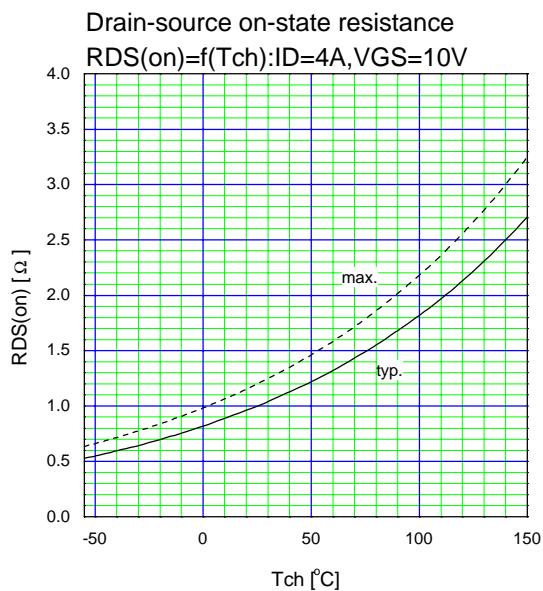


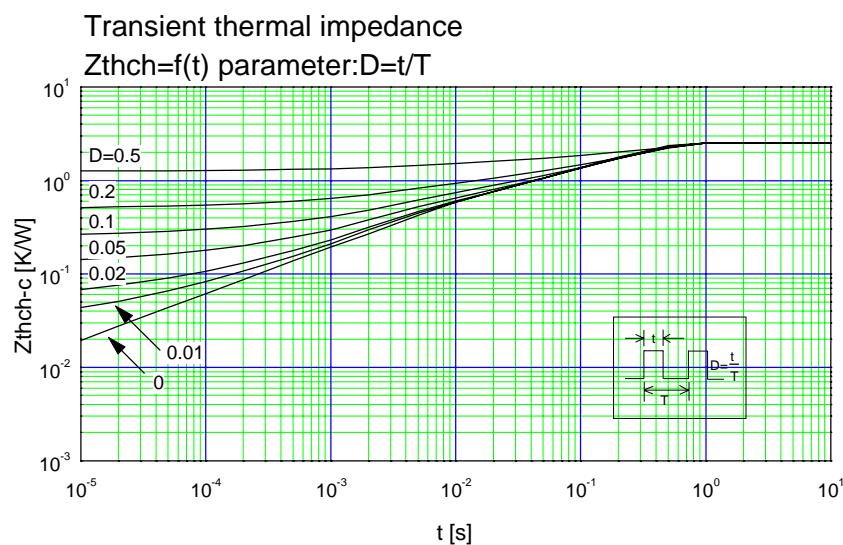
## ■ Equivalent circuit schematic



## Characteristics







保守移行機種  
Not recommend for new design.